



MAAPGM0027 RO-P-DS-3097 Preliminary Information

Features

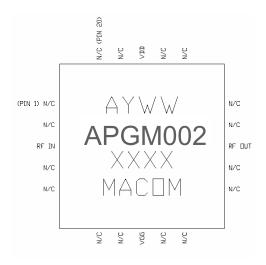
- ◆ 1.0W Operation
- ◆ Variable Drain Voltage (4-10V) Operation
- ♦ MSAG™ Process
- ◆ 5x5 mm 20 Lead MLP Package

Description

The MAAPGM0027 is a packaged, 2-stage, 1.0 W power amplifier with on-chip bias networks in a 20 lead MLP package, allowing easy assembly. This product is fully matched to 50 ohms on both the input and output. It can be used as a power amplifier stage or as a driver stage in high power applications.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate MESFET Process, each device is 100% RF tested on wafer to ensure performance compliance.

M/A-COM's MSAG™ process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors, multiple implant capability enabling power, low-noise, switch and digital FETs on a single chip, and polyimide scratch protection for ease of use with automated manufacturing processes. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



Primary Applications

- ♦ Wireless Local Loop 3.4-3.6 GHz
- ♦ MMDS 2.5-2.7 GHz
- Radar

Maximum Operating Conditions ¹

Parameter	Symbol	Absolute Maximum	Units
Input Power	P _{IN}	15.0	dBm
Drain Supply Voltage	V_{DD}	+12.0	V
Gate Supply Voltage	V_{GG}	-3.5	V
Quiescent Drain Current (No RF, 40% IDSS)	I _{DQ}	360	mA
Quiescent DC Power Dissipated (No RF)	P_{DISS}	3.3	W
Junction Temperature	T_J	180	°C
Storage Temperature	T _{STG}	-55 to +150	°C

1. Operation outside of these ranges may reduce product reliability.

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Recommended Operating Conditions

Characteristic	Symbol	Min	Тур	Max	Unit
Drain Supply Voltage	V_{DD}	4.0	8.0	10.0	V
Gate Supply Voltage	V_{GG}	-2.4	-2.0	-1.3	V
Input Power	P _{IN}		10.0	13.0	dBm
Junction Temperature	T_J			150	°C
Thermal Resistance	Θ _{JC}		26.1		°C/W
Package Base Temperature	T _B			Note 2	°C

^{2.} Maximum Package Base Temperature = 150°C — $\Theta_{JC}^* V_{DD} * I_{DQ}$

Electrical Characteristics: $T_B = 40^{\circ}C^3$, $Z_0 = 50$ W, $V_{DD} = 8V$, $I_{DQ} \approx 230$ mA⁴, $P_{in} = 10$ dBm, $R_G \approx 300$ Ω

Parameter	Symbol	Typical*	Units
Bandwidth	f	2.0-4.0	GHz
Output Power	POUT	30	dBm
Power Added Efficiency	PAE	35	%
1-dB Compression Point	P1dB	29	dBm
Small Signal Gain	G	22	dB
Input VSWR	VSWR	2:1	
Output VSWR	VSWR	1.8:1	_
Gate Supply Current	I _{GG}	<4	mA
Drain Supply Current	I _{DD}	<400	mA
Noise Figure	NF	6	dB
2 nd Harmonic	2f	-15	dBc
3 rd Harmonic	3f	-25	dBc
Output Third Order Intercept	ОТОІ	37	dBm
3 rd Order Intermodulation Distortion, Single Carrier Level = 21 dBm	IM3	-12	dBm
5 th Order Intermodulation Distortion, Single Carrier Level = 21 dBm	IM5	-36	dBm

3. $T_B = MMIC$ base temperature.

4. Adjust V_{GG} between -2.4 to -1.3V to achieve indicated I_{DQ} .



ATTENTION Static-Sensitive Devices Handling Precautions Required

Operating Instructions

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

- 1. Apply $V_{GG} \approx -1.7V$, $V_{DD} = 0 V$.
- 2. Ramp V_{DD} to desired voltage, typically 8 V.
- 3. Adjust V_{GG} to set I_{DQ} , (See Note 3 above).
- 4. Set RF input.
- 5. Power down sequence in reverse. Turn V_{GG} off last.

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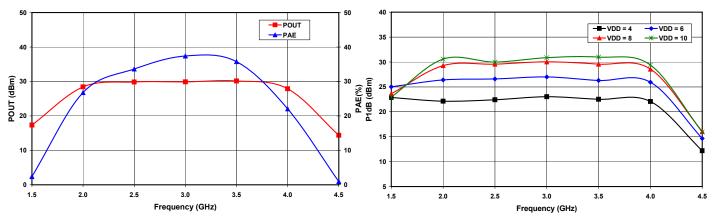
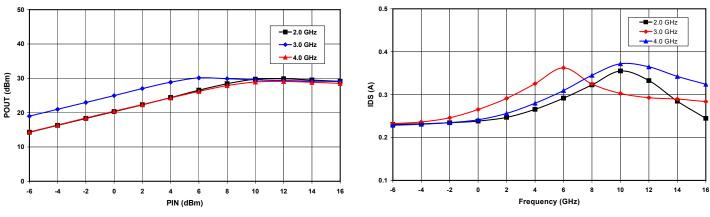


Figure 1. Output Power and Power Added Efficiency vs. Frequency at V_{DD} = 8V and P_{in} = 8 dBm

Figure 2. 1dB Compression Point vs. Drain Voltage



10

1.5

POUT

Figure 3. Output Power vs. Input Power at V_{DD} = 8V

Figure 4. Drain Current vs. Input Power at V_{DD} = 8V

Figure 5. Saturated Output Power and Power Added Efficiency vs. Drain Voltage at $\rm f_{o}$ = 3.5 GHz

Drain Voltage (volts)

 $Frequency \, (GHz)$ $Figure \,\, 6. \,\, Small \,\, Signal \,\, Gain \,\, and \,\, VSWR \,\, vs. \,\, Frequency \,\, at \,\, V_{DD} = 8V.$

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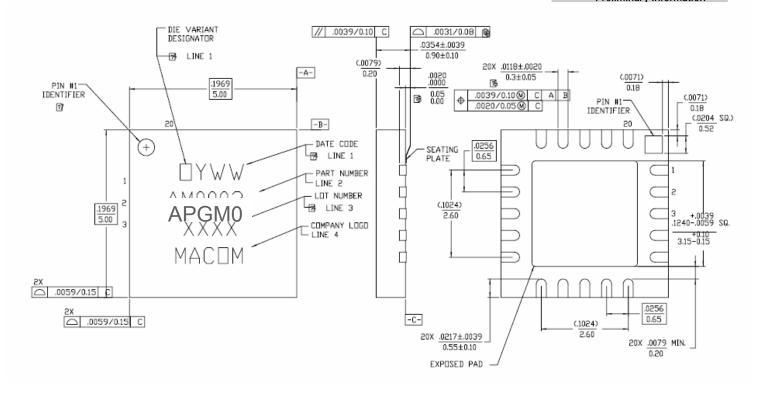


Figure 7. 5x5 mm 20-Lead MLP.

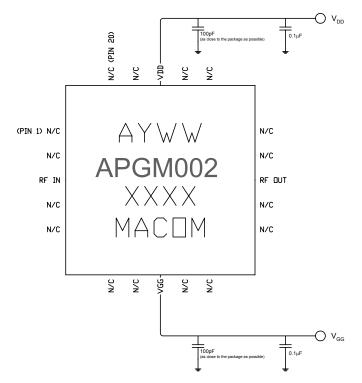


Figure 8. Recommended Bias Configuration.

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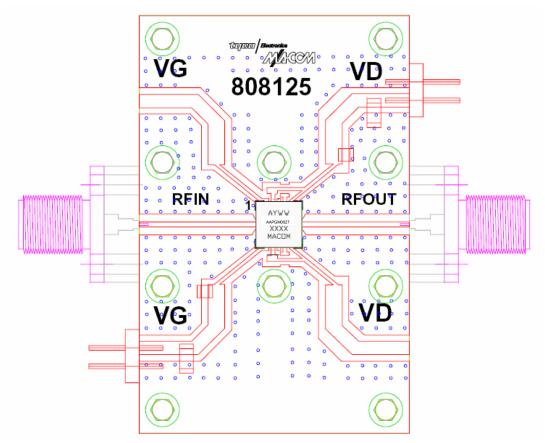


Figure 9. Demonstration Board PN MAAPGM0027-SMB (available upon request).

Refer to M/A-COM Application Note **Surface Mounting Instructions for FQFP-N Packages #S2083*** for assembly guidelines.

Application Notes can be found by going to the Site Search Page on M/A-COM's web page (http://www.macom.com/search/search.jsp) and searching for the required Application Note.

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